ULN2004AI HIGH-VOLTAGE HIGH-CURRENT DARLINGTON TRANSISTOR ARRAY

SLRS055 - APRIL 2004

- 500-mA-Rated Collector Current (Single Output)
- High-Voltage Outputs . . . 50 V
- Output Clamp Diodes
- Inputs Compatible With Various Types of Logic
- Relay-Driver Applications

16**∏** 1C 1B l 2B **∏** 15 **∏** 2C 3B **∏** 3 14**∏** 3C 4B 🛮 4 13 4C 5B **∏** 5 12**∏** 5C 6В П 6 11 **∏** 6C 7B **∏** 7 10 7C E [] 8 9 COM

D, N, OR NS PACKAGE

(TOP VIEW)

description/ordering information

The ULN2004AI is a high-voltage, high-current Darlington transistor array. This device consists of seven npn Darlington pairs that feature

high-voltage outputs with common-cathode clamp diodes for switching inductive loads. The collector-current rating of a single Darlington pair is 500 mA. The Darlington pairs can be paralleled for higher-current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers.

The ULN2004AI has a 10.5-k Ω series base resistor for each Darlington pair for operation directly with TTL or 5-V CMOS devices.

ORDERING INFORMATION

TA	PACKAG	_{SE} †	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP (N)	Tube of 25	ULN2004AIN	ULN2004AIN
4000 +- 40500	SOIC (D)	Tube of 40	ULN2004AID	ULN2004AI
–40°C to 105°C	30IC (D)	Reel of 2500	ULN2004AIDR	ULINZUU4AI
	SOP (NS)	Reel of 2000	ULN2004AINSR	ULN2004AI

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

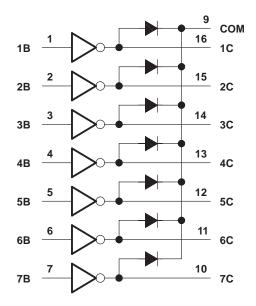


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

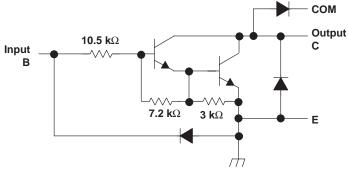


SLRS055 - APRIL 2004

logic diagram



schematics (each Darlington pair)



All resistor values shown are nominal.



ULN2004AI HIGH-VOLTAGE HIGH-CURRENT DARLINGTON TRANSISTOR ARRAY

SLRS055 - APRIL 2004

absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)†

Collector-emitter voltage	50 V
Clamp diode reverse voltage (see Note 1)	50 V
Input voltage, V _I (see Note 1)	30 V
Peak collector current (see Notes 2 and 4)	500 mA
Output clamp current, I _{OK}	500 mA
Total emitter-terminal current	
Operating free-air temperature range, T _A	–40°C to 105°C
Package thermal impedance, θ _{JA} (see Notes 2 and 3): D package	
N package	67°C/W
NS package	64°C/W
Operating virtual junction temperature, T _J	150°C
Storage temperature range, T _{stq}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.
 - 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

electrical characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST FIGURE	TEST C	CONDITIONS	MIN TY	P MAX	UNIT	
				I _C = 125 mA		5		
V/	On state input valte as	_) 	I _C = 200 mA		6] ,,	
V _{I(on)}	On-state input voltage	6	V _{CE} = 2 V	$I_C = 275 \text{ mA}$		7	V	
				$I_C = 350 \text{ mA}$		8		
			I _I = 250 μA,	I _C = 100 mA	0.	9 1.1		
V _{CE(sat)}	Collector-emitter saturation voltage	5	$I_I = 350 \mu A$,	I _C = 200 mA		1 1.3	V	
			I _I = 500 μA,	I _C = 350 mA	1.	2 1.6		
ICEX	Collector cutoff current	1	V _{CE} = 50 V,	I _I = 0		50	μА	
٧F	Clamp forward voltage	8	I _F = 350 mA		1.	7 2	V	
		4	V _I = 5 V		0.3	5 0.5		
II	Input current	4	V _I = 12 V			1 1.45	mA	
I _R	Clamp reverse current	7	V _R = 50 V			50	μΑ	
Ci	Input capacitance		$V_{I} = 0,$	f = 1 MHz	1	5 25	pF	

ULN2004AI **HIGH-VOLTAGE HIGH-CURRENT DARLINGTON** TRANSISTOR ARRAY SLRS055 – APRIL 2004

electrical characteristics, $T_A = -40^{\circ} C$ to $105^{\circ} C$

	PARAMETER	TEST FIGURE	TEST (CONDITIONS	MIN	TYP	MAX	UNIT
				I _C = 125 mA			5	
	On otata inmuturaltana	6		I _C = 200 mA			6	V
V _{I(on)}	On-state input voltage	0	V _{CE} = 2 V	$I_C = 275 \text{ mA}$			7	V
				$I_C = 350 \text{ mA}$			8	
			$I_I = 250 \mu A$,	$I_C = 100 \text{ mA}$		0.9	1.1	
VCE(sat)	Collector-emitter saturation voltage	5	$I_I = 350 \mu A$,	$I_C = 200 \text{ mA}$		1	1.3	V
` ′			$I_I = 500 \mu A$,	$I_C = 350 \text{ mA}$		1.2	1.6	
		1	V _{CE} = 50 V,	I _I = 0			50	
ICEX	Collector cutoff current	2	50.1/	I _I = 0			100	μΑ
			V _{CE} = 50 V	V _I = 1 V			500	
VF	Clamp forward voltage	8	$I_F = 350 \text{ mA}$			1.7	2	V
I _{I(off)}	Off-state input current	3	$V_{CE} = 50 \text{ V},$	$I_C = 500 \mu A$	50	65		μΑ
1.	Input current		V _I = 5 V			0.35	0.5	m 1
l _l			V _I = 12 V			1	1.45	mA
I_{R}	Clamp reverse current	7	V _R = 50 V				100	μΑ
Ci	Input capacitance		$V_{I} = 0,$	f = 1 MHz		15	25	pF

switching characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output	See Figure 8		0.25	1	μs
tPHL	Propagation delay time, high- to low-level output	See Figure 8		0.25	1	μs
Vон	High-level output voltage after switching	$V_S = 50 \text{ V}, \qquad I_O \approx 300 \text{ mA},$ See Figure 9	V _S -20			mV

switching characteristics, $T_{\mbox{\scriptsize A}}$ = $-40^{\circ}\mbox{\scriptsize C}$ to $105^{\circ}\mbox{\scriptsize C}$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output	See Figure 8		1	10	μs
tPHL	Propagation delay time, high- to low-level output	See Figure 8		1	10	μs
Vон	High-level output voltage after switching	$V_S = 50 \text{ V}, \qquad I_O \approx 300 \text{ mA},$ See Figure 9	V _S - 500			mV



PARAMETER MEASUREMENT INFORMATION

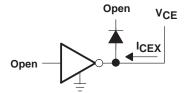


Figure 1. I_{CEX} Test Circuit

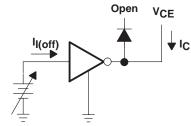
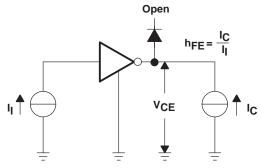


Figure 3. I_{I(off)} Test Circuit



NOTE: I_I is fixed for measuring $V_{\text{CE(sat)}}$, variable for measuring h_{FE}.

Figure 5. h_{FE}, V_{CE(sat)} Test Circuit

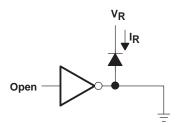


Figure 7. I_R Test Circuit

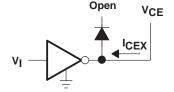


Figure 2. I_{CEX} Test Circuit

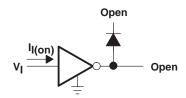


Figure 4. I_I Test Circuit

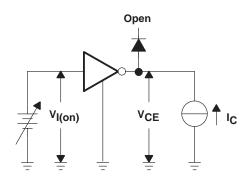


Figure 6. V_{I(on)} Test Circuit

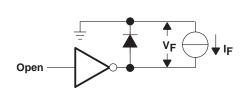


Figure 8. V_F Test Circuit

PARAMETER MEASUREMENT INFORMATION

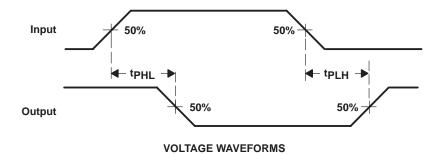
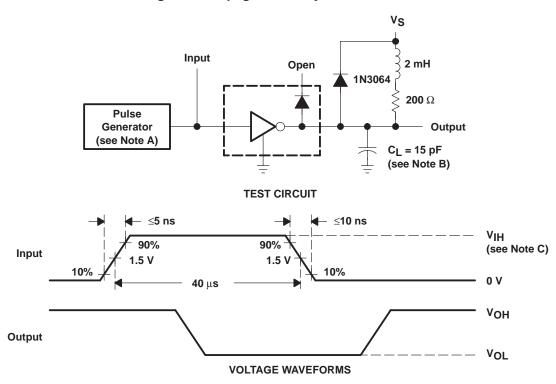


Figure 9. Propagation Delay-Time Waveforms



NOTES: A. The pulse generator has the following characteristics: PRR = 12.5 kHz, Z_O = 50 Ω .

- B. C_L includes probe and jig capacitance.
- C. For testing, $\dot{V}_{IH} = 3 \text{ V}$

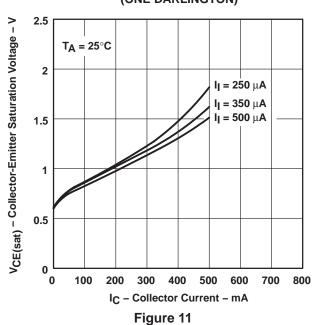
Figure 10. Latch-Up Test Circuit and Voltage Waveforms



SLRS055 - APRIL 2004

TYPICAL CHARACTERISTICS

COLLECTOR-EMITTER
SATURATION VOLTAGE
vs
COLLECTOR CURRENT
(ONE DARLINGTON)



COLLECTOR-EMITTER
SATURATION VOLTAGE
vs
TOTAL COLLECTOR CURRENT
(TWO DARLINGTONS IN PARALLEL)

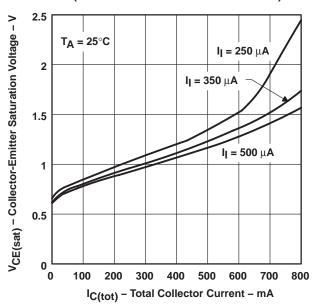


Figure 12

COLLECTOR CURRENT

INPUT CURRENT 500 $R_L = 10 \Omega$ 450 T_A = 25°C 400 I_C - Collector Current - mA V_S = 10 V 350 V_S = 8 V 300 250 200 150 100 50 0 0 100 25 50 75 125 150 175 200 I_I - Input Current - μA

Figure 13



SLRS055 - APRIL 2004

APPLICATION INFORMATION

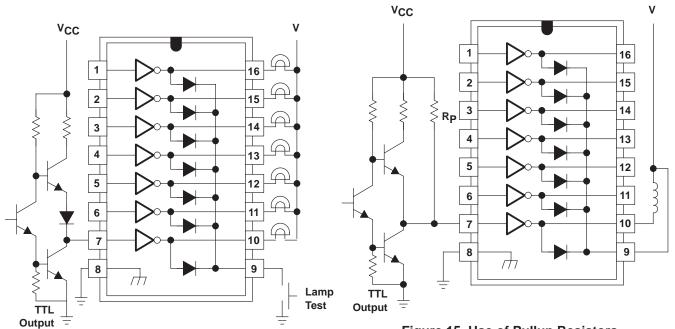


Figure 14. TTL to Load

Figure 15. Use of Pullup Resistors to Increase Drive Current







10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pine	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
Orderable Bevioe	(1)	r dokage Type	Drawing		Qty	(2)	(6)	(3)	op remp (o)	(4/5)	Campics
ULN2004AID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2004AI	Samples
ULN2004AIDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2004AI	Samples
ULN2004AIDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2004AI	Samples
ULN2004AIN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 105	ULN2004AIN	Samples
ULN2004AINSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2004AI	Samples
ULN2004AINSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2004AI	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

10-Jun-2014

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 26-Jan-2013

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
Ī	ULN2004AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ſ	ULN2004AINSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1

www.ti.com 26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ULN2004AIDR	SOIC	D	D 16 25		333.2	345.9	28.6
ULN2004AINSR	SO	NS	16	2000	367.0	367.0	38.0

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom Amplifiers amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com/omap

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>